

## 850MHz, Low Distortion Programmable Gain Buffer Amplifier

November 1996

### Features

- User Programmable for Closed-Loop Gains of +1, -1 or +2 without Use of External Resistors
- Wide -3dB Bandwidth ..... 850MHz
- Very Fast Slew Rate ..... 2400V/ $\mu$ s
- Fast Settling Time (0.1%) ..... 11ns
- High Output Current ..... 60mA
- Excellent Gain Accuracy ..... 0.99V/V
- Overdrive Recovery ..... <10ns
- Standard Operational Amplifier Pinout

### Applications

- RF/IF Processors
- Driving Flash A/D Converters
- High-Speed Communications
- Impedance Transformation
- Line Driving
- Video Switching and Routing
- Radar Systems
- Medical Imaging Systems
- Related Literature
  - AN9507, Video Cable Drivers Save Board Space

### Description

The HFA1112 is a closed loop Buffer featuring user programmable gain and ultra high speed performance. Manufactured on Harris' proprietary complementary bipolar UHF-1 process, the HFA1112 offers a wide -3dB bandwidth of 850MHz, very fast slew rate, excellent gain flatness, low distortion and high output current.

A unique feature of the pinout allows the user to select a voltage gain of +1, -1, or +2, without the use of any external components. Gain selection is accomplished via connections to the inputs, as described in the "Application Information" section. The result is a more flexible product, fewer part types in inventory, and more efficient use of board space.

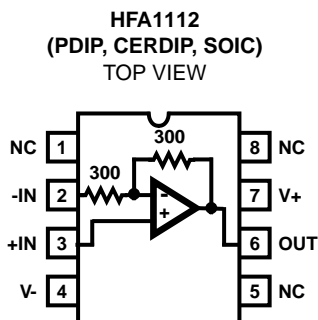
Compatibility with existing op amp pinouts provides flexibility to upgrade low gain amplifiers, while decreasing component count. Unlike most buffers, the standard pinout provides an upgrade path should a higher closed loop gain be needed at a future date.

This amplifier is available with programmable output limiting as the HFA1113. For applications requiring a standard buffer pinout, please refer to the HFA1110 datasheet. For Military product, refer to the HFA1112/883 data sheet.

### Ordering Information

PART NUMBER (BRAND)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HFA1112IJ	-40 to 85	8 Ld CERDIP	F8.3A
HFA1112IP	-40 to 85	8 Ld PDIP	E8.3
HFA1112IB (H1112I)	-40 to 85	8 Ld SOIC	M8.15
HFA11XXEVAL	High Speed Op Amp DIP Evaluation Board		

### Pinout



### Pin Descriptions

NAME	PIN NUMBER	DESCRIPTION
NC	1, 5, 8	No Connection
-IN	2	Inverting Input
+IN	3	Non-Inverting Input
V-	4	Negative Supply
OUT	6	Output
V+	7	Positive Supply

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## Absolute Maximum Ratings

Voltage Between V+ and V- .....	12V
Input Voltage .....	V <sub>SUPPLY</sub>
Output Current .....	60mA

## Operating Conditions

Temperature Range .....	-40°C to 85°C
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## Thermal Information

Thermal Resistance (Typical, Note 1)	$\theta_{JA}$ (°C/W)	$\theta_{JC}$ (°C/W)
CERDIP Package .....	120	35
PDIP Package .....	98	N/A
SOIC Package .....	170	N/A
Maximum Junction Temperature (Ceramic Package and Die) ..	175°C	
Maximum Junction Temperature (Plastic Package) .....	150°C	
Maximum Storage Temperature Range .....	-65°C to 150°C	
Maximum Lead Temperature (Soldering 10s) .....	300°C (SOIC - Lead Tips Only)	

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

### NOTE:

- $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

## Electrical Specifications V<sub>SUPPLY</sub> = ±5V, A<sub>V</sub> = +1, R<sub>L</sub> = 100Ω, Unless Otherwise Specified

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN	TYP	MAX	UNITS
<b>INPUT CHARACTERISTICS</b>						
Output Offset Voltage		25	-	8	25	mV
		Full	-	-	35	mV
Output Offset Voltage Drift		Full	-	10	-	μV/°C
PSRR		25	39	45	-	dB
		Full	35	-	-	dB
Input Noise Voltage (Note 3)	100kHz	25	-	9	-	nV/√Hz
Non-Inverting Input Noise Current (Note 3)	100kHz	25	-	37	-	pA/√Hz
Non-Inverting Input Bias Current		25	-	25	40	μA
		Full	-	-	65	μA
Non-Inverting Input Resistance		25	25	50	-	kΩ
Inverting Input Resistance (Note 2)		25	240	300	360	Ω
Input Capacitance		25	-	2	-	pF
Input Common Mode Range		Full	±2.5	±2.8	-	V
<b>TRANSFER CHARACTERISTICS</b>						
Gain	A <sub>V</sub> = +1, V <sub>IN</sub> = +2V	25	0.980	0.990	1.02	V/V
		Full	0.975	-	1.025	V/V
Gain	A <sub>V</sub> = +2, V <sub>IN</sub> = +1V	25	1.96	1.98	2.04	V/V
		Full	1.95	-	2.05	V/V
DC Non-Linearity (Note 3)	A <sub>V</sub> = +2, ±2V Full Scale	25	-	0.02	-	%
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage (Note 3)	A <sub>V</sub> = -1	25	±3.0	±3.3	-	V
		Full	±2.5	±3.0	-	V
Output Current (Note 3)	R <sub>L</sub> = 50Ω	25, 85	50	60	-	mA
		-40	35	50	-	mA
Closed Loop Output Impedance	DC, A <sub>V</sub> = +2	25	-	0.3	-	Ω
<b>POWER SUPPLY CHARACTERISTICS</b>						
Supply Voltage Range		Full	±4.5	-	±5.5	V
Supply Current (Note 3)		25	-	21	26	mA
		Full	-	-	33	mA

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## Electrical Specifications $V_{SUPPLY} = \pm 5V$ , $A_V = +1$ , $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN	TYP	MAX	UNITS
<b>AC CHARACTERISTICS</b>						
-3dB Bandwidth ( $V_{OUT} = 0.2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	450	800	-	MHz
	$A_V = +1$	25	500	850	-	MHz
	$A_V = +2$	25	350	550	-	MHz
Slew Rate ( $V_{OUT} = 5V_{P-P}$ , Note 2)	$A_V = -1$	25	1500	2400	-	V/ $\mu$ s
	$A_V = +1$	25	800	1500	-	V/ $\mu$ s
	$A_V = +2$	25	1100	1900	-	V/ $\mu$ s
Full Power Bandwidth ( $V_{OUT} = 5V_{P-P}$ , Note 3)	$A_V = -1$	25	-	300	-	MHz
	$A_V = +1$	25	-	150	-	MHz
	$A_V = +2$	25	-	220	-	MHz
Gain Flatness (to 30MHz, Notes 2, 3)	$A_V = -1$	25	-	$\pm 0.02$	-	dB
	$A_V = +1$	25	-	$\pm 0.1$	-	dB
	$A_V = +2$	25	-	$\pm 0.015$	$\pm 0.04$	dB
Gain Flatness (to 50MHz, Notes 2, 3)	$A_V = -1$	25	-	$\pm 0.05$	-	dB
	$A_V = +1$	25	-	$\pm 0.2$	-	dB
	$A_V = +2$	25	-	$\pm 0.036$	$\pm 0.08$	dB
Gain Flatness (to 100MHz, Notes 2, 3)	$A_V = -1$	25	-	$\pm 0.10$	-	dB
	$A_V = +2$	25	-	$\pm 0.07$	$\pm 0.22$	dB
Linear Phase Deviation (to 100MHz, Note 3)	$A_V = -1$	25	-	$\pm 0.13$	-	Degrees
	$A_V = +1$	25	-	$\pm 0.83$	-	Degrees
	$A_V = +2$	25	-	$\pm 0.05$	-	Degrees
2nd Harmonic Distortion (30MHz, $V_{OUT} = 2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	-	-52	-	dBc
	$A_V = +1$	25	-	-57	-	dBc
	$A_V = +2$	25	-	-52	-45	dBc
3rd Harmonic Distortion (30MHz, $V_{OUT} = 2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	-	-71	-	dBc
	$A_V = +1$	25	-	-73	-	dBc
	$A_V = +2$	25	-	-72	-65	dBc
2nd Harmonic Distortion (50MHz, $V_{OUT} = 2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	-	-47	-	dBc
	$A_V = +1$	25	-	-53	-	dBc
	$A_V = +2$	25	-	-47	-40	dBc
3rd Harmonic Distortion (50MHz, $V_{OUT} = 2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	-	-63	-	dBc
	$A_V = +1$	25	-	-68	-	dBc
	$A_V = +2$	25	-	-65	-55	dBc
2nd Harmonic Distortion (100MHz, $V_{OUT} = 2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	-	-41	-	dBc
	$A_V = +1$	25	-	-50	-	dBc
	$A_V = +2$	25	-	-42	-35	dBc
3rd Harmonic Distortion (100MHz, $V_{OUT} = 2V_{P-P}$ , Notes 2, 3)	$A_V = -1$	25	-	-55	-	dBc
	$A_V = +1$	25	-	-49	-	dBc
	$A_V = +2$	25	-	-62	-45	dBc
3rd Order Intercept ( $A_V = +2$ , Note 3)	100MHz	25	-	28	-	dBm
	300MHz	25	-	13	-	dBm
1dB Compression ( $A_V = +2$ , Note 3)	100MHz	25	-	19	-	dBm
	300MHz	25	-	12	-	dBm

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## Electrical Specifications $V_{SUPPLY} = \pm 5V$ , $A_V = +1$ , $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN	TYP	MAX	UNITS
Reverse Isolation (S <sub>12</sub> , Note 3)	40MHz	25	-	-70	-	dB
	100MHz	25	-	-60	-	dB
	600MHz	25	-	-32	-	dB
<b>TRANSIENT CHARACTERISTICS</b>						
Rise Time (V <sub>OUT</sub> = 0.5V Step, Note 2)	A <sub>V</sub> = -1	25	-	500	800	ps
	A <sub>V</sub> = +1	25	-	480	750	ps
	A <sub>V</sub> = +2	25	-	700	1000	ps
Rise Time (V <sub>OUT</sub> = 2V Step)	A <sub>V</sub> = -1	25	-	0.82	-	ns
	A <sub>V</sub> = +1	25	-	1.06	-	ns
	A <sub>V</sub> = +2	25	-	1.00	-	ns
Overshoot (V <sub>OUT</sub> = 0.5V Step, Input t <sub>R</sub> /t <sub>F</sub> = 200ps, Notes 2, 3, 4)	A <sub>V</sub> = -1	25	-	12	30	%
	A <sub>V</sub> = +1	25	-	45	65	%
	A <sub>V</sub> = +2	25	-	6	20	%
0.1% Settling Time (Note 3)	V <sub>OUT</sub> = 2V to 0V	25	-	11	-	ns
0.05% Settling Time	V <sub>OUT</sub> = 2V to 0V	25	-	15	-	ns
Overdrive Recovery Time	V <sub>IN</sub> = 5V <sub>P-P</sub>	25	-	8.5	-	ns
Differential Gain	A <sub>V</sub> = +1, 3.58MHz, R <sub>L</sub> = 150Ω	25	-	0.03	-	%
	A <sub>V</sub> = +2, 3.58MHz, R <sub>L</sub> = 150Ω	25	-	0.02	-	%
Differential Phase	A <sub>V</sub> = +1, 3.58MHz, R <sub>L</sub> = 150Ω	25	-	0.05	-	Degrees
	A <sub>V</sub> = +2, 3.58MHz, R <sub>L</sub> = 150Ω	25	-	0.04	-	Degrees

### NOTES:

- This parameter is not tested. The limits are guaranteed based on lab characterization, and reflect lot-to-lot variation.
- See Typical Performance Curves for more information.
- Overshoot decreases as input transition times increase, especially for A<sub>V</sub> = +1. Please refer to Typical Performance Curves.

## Application Information

### Closed Loop Gain Selection

The HFA1112 features a novel design which allows the user to select from three closed loop gains, without any external components. The result is a more flexible product, fewer part types in inventory, and more efficient use of board space.

This "buffer" operates in closed loop gains of -1, +1, or +2, and gain selection is accomplished via connections to the ±inputs. Applying the input signal to +IN and floating -IN selects a gain of +1, while grounding -IN selects a gain of +2. A gain of -1 is obtained by applying the input signal to -IN with +IN grounded.

The table below summarizes these connections:

GAIN (A <sub>CL</sub> )	CONNECTIONS	
	+INPUT (PIN 3)	-INPUT (PIN 2)
-1	GND	Input
+1	Input	NC (Floating)
+2	Input	GND

## PC Board Layout

The frequency response of this amplifier depends greatly on the amount of care taken in designing the PC board. **The use of low inductance components such as chip resistors and chip capacitors is strongly recommended, while a solid ground plane is a must!**

Attention should be given to decoupling the power supplies. A large value (10μF) tantalum in parallel with a small value (0.1μF) chip capacitor works well in most cases.

Terminated microstrip signal lines are recommended at the input and output of the device. Capacitance directly on the output must be minimized, or isolated as discussed in the next section.

For unity gain applications, care must also be taken to minimize the capacitance to ground seen by the amplifier's inverting input. At higher frequencies this capacitance will tend to short the -INPUT to GND, resulting in a closed loop gain which increases with frequency. This will cause excessive high frequency peaking and potentially other problems as well.

An example of a good high frequency layout is the Evaluation Board shown in Figure 2.

### Driving Capacitive Loads

Capacitive loads, such as an A/D input, or an improperly terminated transmission line will degrade the amplifier's phase margin resulting in frequency response peaking and possible oscillations. In most cases, the oscillation can be avoided by placing a resistor ( $R_S$ ) in series with the output prior to the capacitance.

Figure 1 details starting points for the selection of this resistor. The points on the curve indicate the  $R_S$  and  $C_L$  combinations for the optimum bandwidth, stability, and settling time, but experimental fine tuning is recommended. Picking a point above or to the right of the curve yields an overdamped response, while points below or left of the curve indicate areas of underdamped performance.

$R_S$  and  $C_L$  form a low pass network at the output, thus limiting system bandwidth well below the amplifier bandwidth of 850MHz. By decreasing  $R_S$  as  $C_L$  increases (as illustrated in the curves), the maximum bandwidth is obtained without sacrificing stability. Even so, bandwidth does decrease as you move to the right along the curve. For example, at  $A_V = +1$ ,  $R_S = 50\Omega$ ,  $C_L = 30pF$ , the overall bandwidth is limited to 300MHz, and bandwidth drops to 100MHz at  $A_V = +1$ ,  $R_S = 5\Omega$ ,  $C_L = 340pF$ .

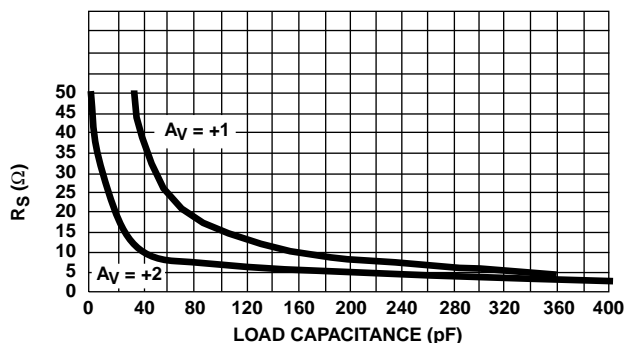


FIGURE 1. RECOMMENDED SERIES OUTPUT RESISTOR vs LOAD CAPACITANCE

### Evaluation Board

The performance of the HFA1112 may be evaluated using the HFA11XX Evaluation Board, slightly modified as follows:

1. Remove the 500 $\Omega$  feedback resistor ( $R_2$ ), and leave the connection open.
2. a. For  $A_V = +1$  evaluation, remove the 500 $\Omega$  gain setting resistor ( $R_1$ ), and leave pin 2 floating.  
b. For  $A_V = +2$ , replace the 500 $\Omega$  gain setting resistor with a 0 $\Omega$  resistor to GND.

The layout and modified schematic of the board are shown in Figure 2.

To order evaluation boards (part number HFA11XXEVAL), please contact your local sales office.

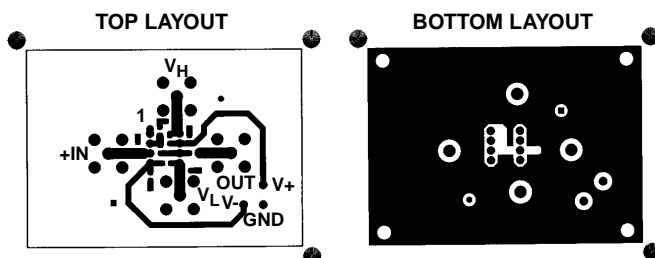
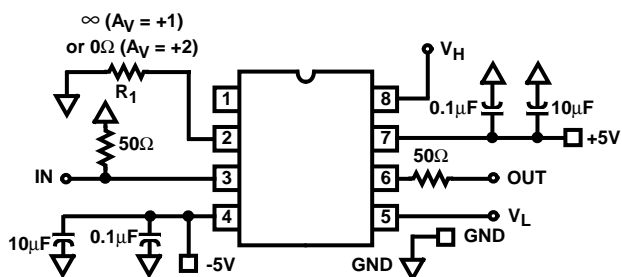


FIGURE 2. EVALUATION BOARD SCHEMATIC AND LAYOUT

**Typical Performance Curves**  $V_{\text{SUPPLY}} = \pm 5\text{V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 100\Omega$ , Unless Otherwise Specified

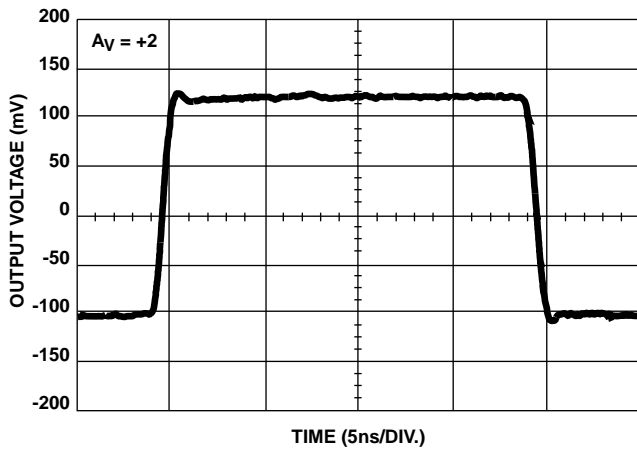


FIGURE 3. SMALL SIGNAL PULSE RESPONSE

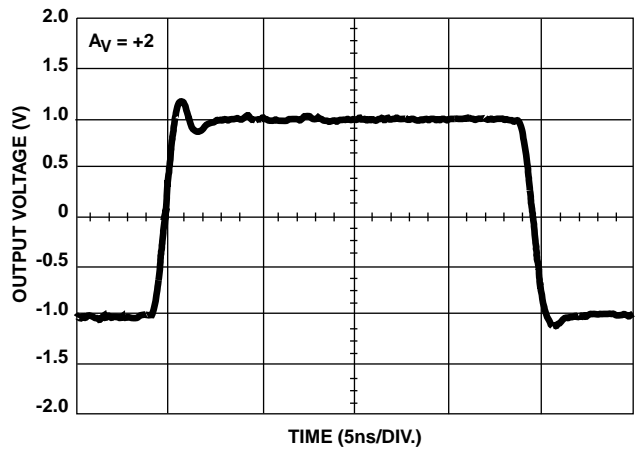


FIGURE 4. LARGE SIGNAL PULSE RESPONSE

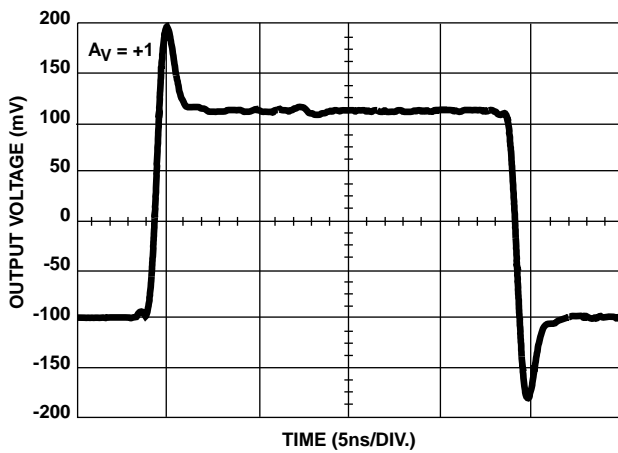


FIGURE 5. SMALL SIGNAL PULSE RESPONSE

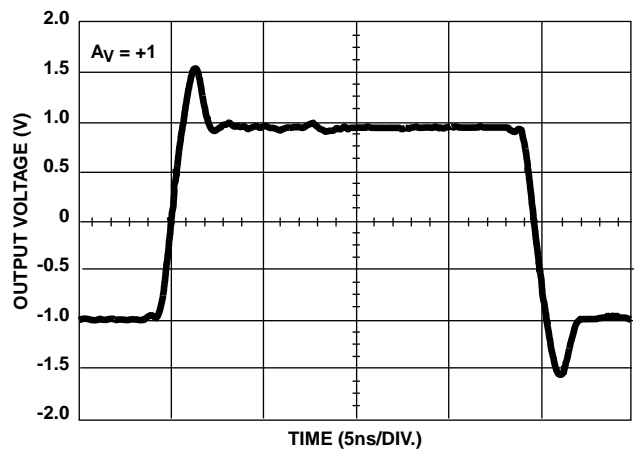


FIGURE 6. LARGE SIGNAL PULSE RESPONSE

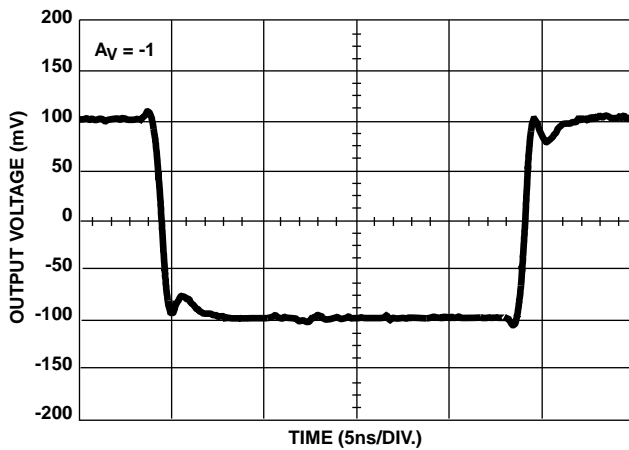


FIGURE 7. SMALL SIGNAL PULSE RESPONSE

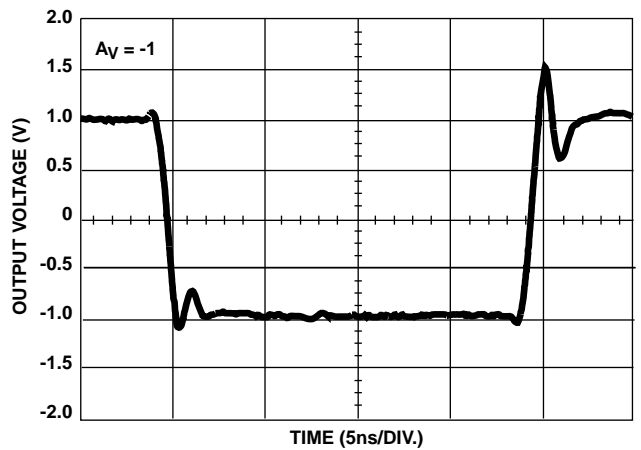


FIGURE 8. LARGE SIGNAL PULSE RESPONSE

**Typical Performance Curves**  $V_{SUPPLY} = \pm 5V$ ,  $T_A = 25^\circ C$ ,  $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

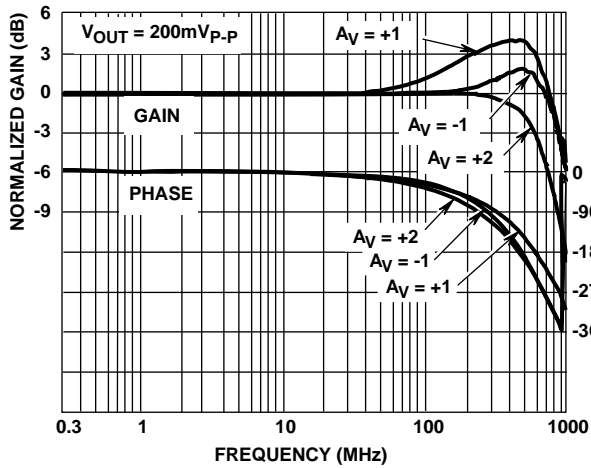


FIGURE 9. FREQUENCY RESPONSE

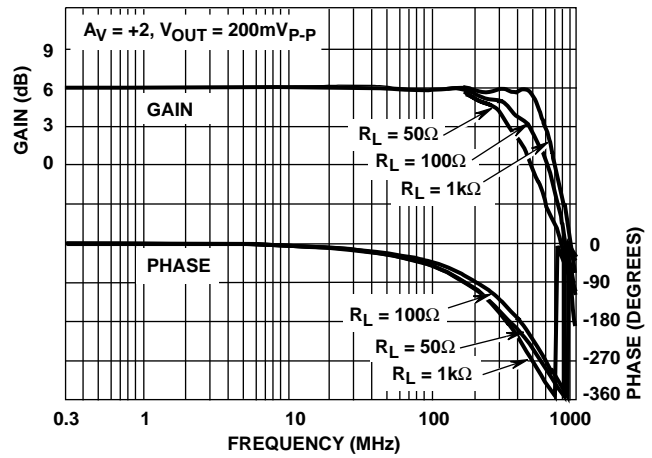


FIGURE 10. FREQUENCY RESPONSE FOR VARIOUS LOAD RESISTORS

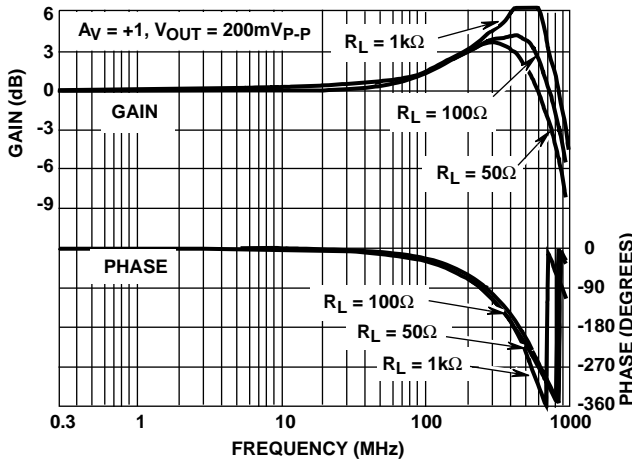


FIGURE 11. FREQUENCY RESPONSE FOR VARIOUS LOAD RESISTORS

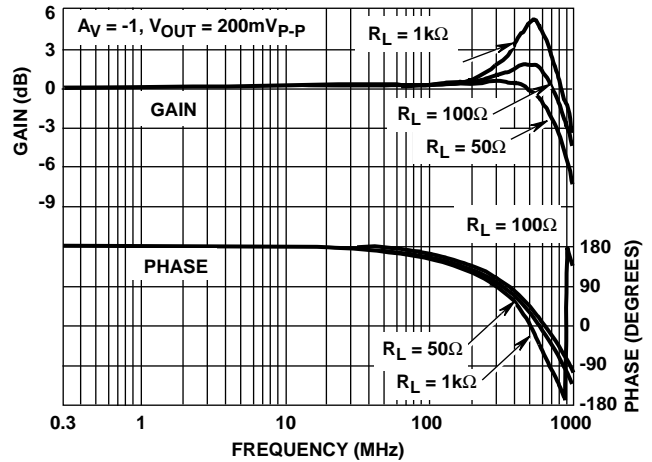


FIGURE 12. FREQUENCY RESPONSE FOR VARIOUS LOAD RESISTORS

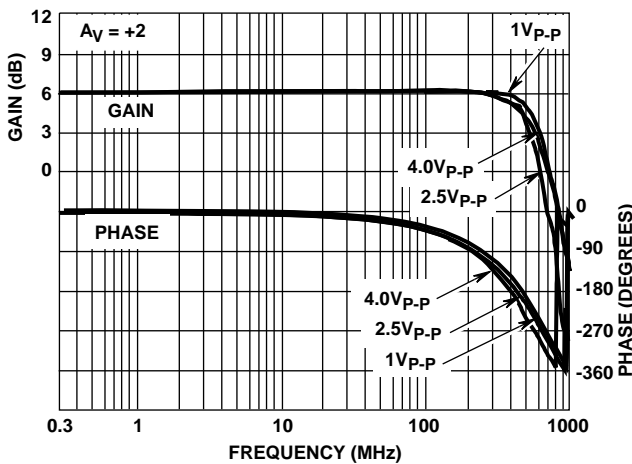


FIGURE 13. FREQUENCY RESPONSE FOR VARIOUS OUTPUT VOLTAGES

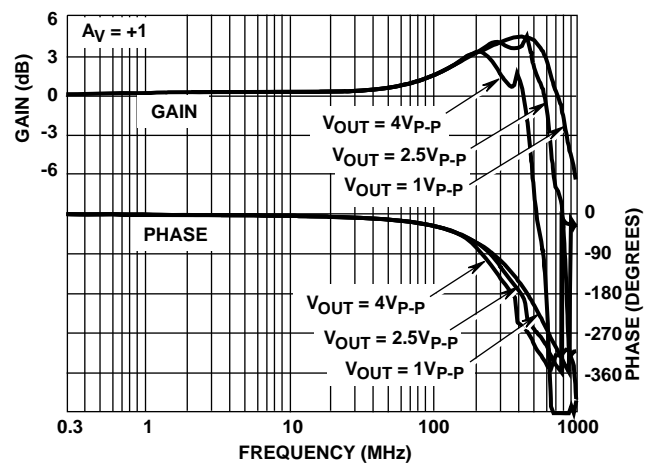


FIGURE 14. FREQUENCY RESPONSE FOR VARIOUS OUTPUT VOLTAGES

**Typical Performance Curves**  $V_{SUPPLY} = \pm 5V$ ,  $T_A = 25^\circ C$ ,  $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

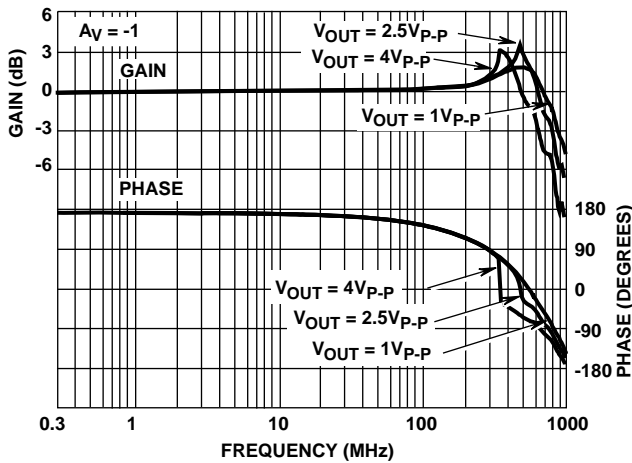


FIGURE 15. FREQUENCY RESPONSE FOR VARIOUS OUTPUT VOLTAGES

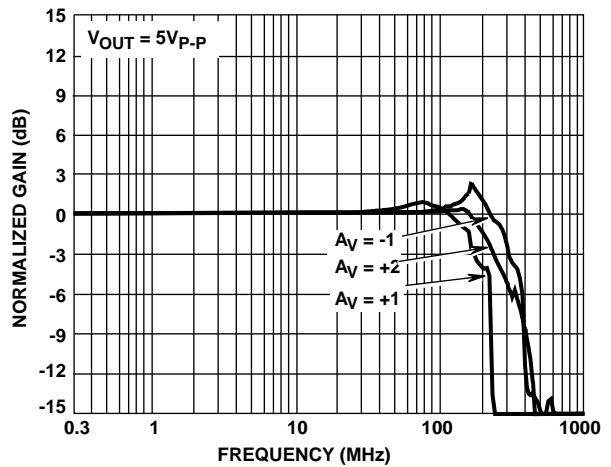


FIGURE 16. FULL POWER BANDWIDTH

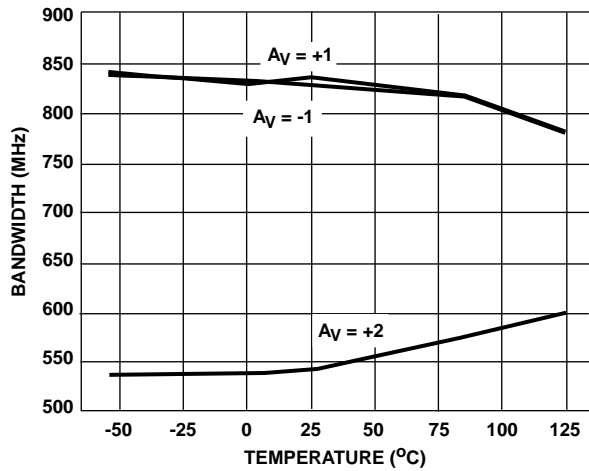


FIGURE 17. -3dB BANDWIDTH vs TEMPERATURE

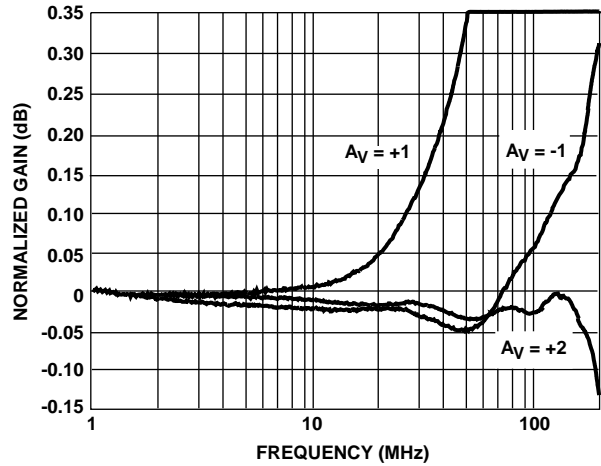


FIGURE 18. GAIN FLATNESS

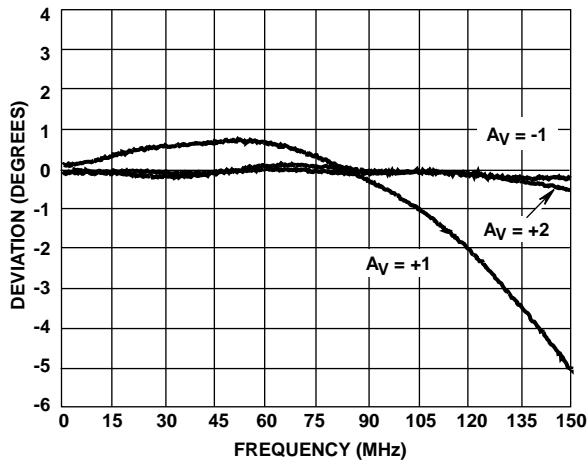


FIGURE 19. DEVIATION FROM LINEAR PHASE

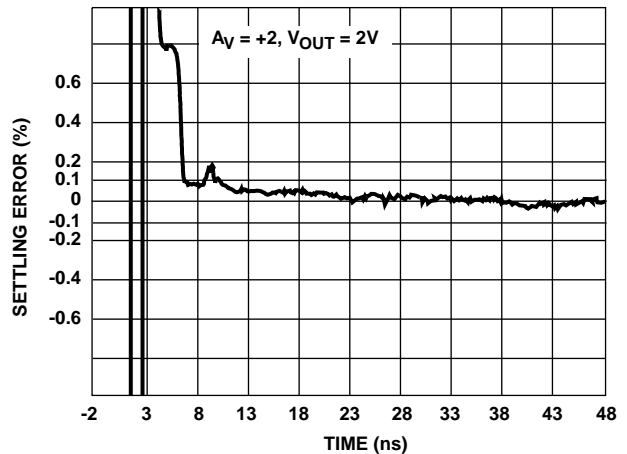


FIGURE 20. SETTLING RESPONSE



**Typical Performance Curves**  $V_{SUPPLY} = \pm 5V$ ,  $T_A = 25^\circ C$ ,  $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

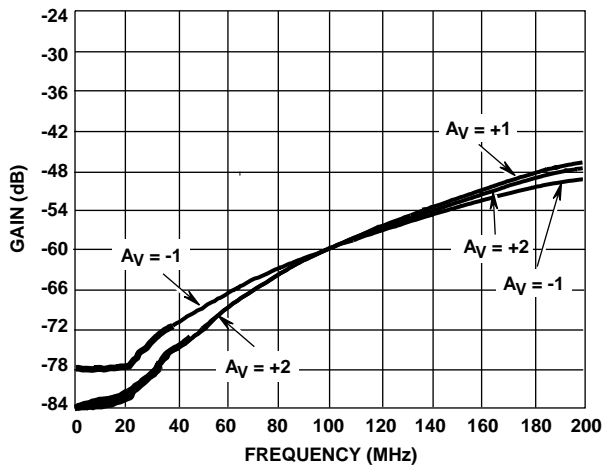


FIGURE 21. LOW FREQUENCY REVERSE ISOLATION ( $S_{12}$ )

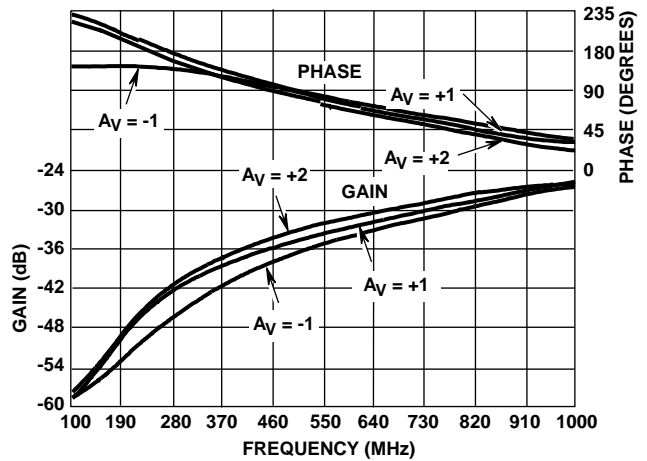


FIGURE 22. HIGH FREQUENCY REVERSE ISOLATION ( $S_{12}$ )

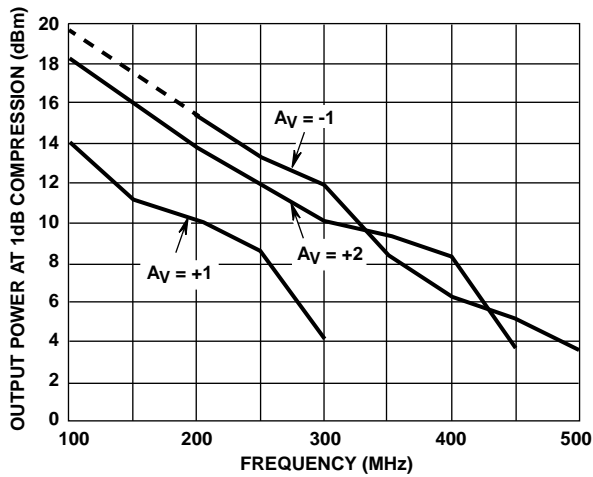


FIGURE 23. 1dB GAIN COMPRESSION vs FREQUENCY

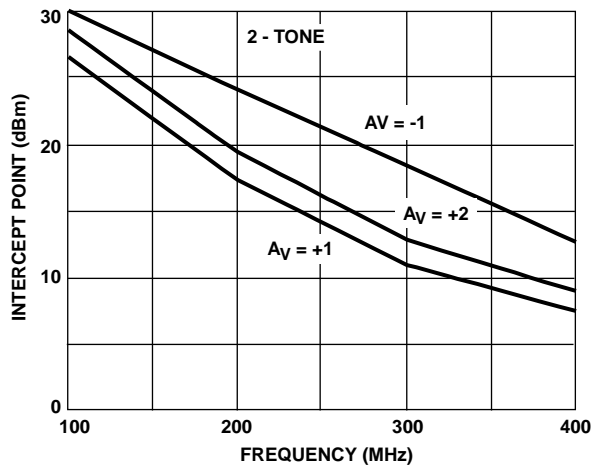


FIGURE 24. 3rd ORDER INTERMODULATION INTERCEPT vs FREQUENCY

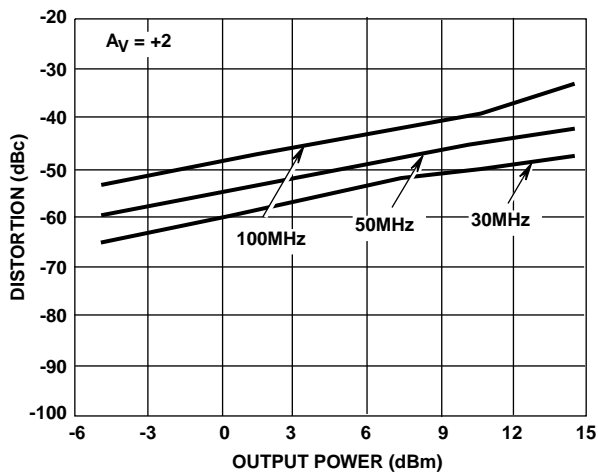


FIGURE 25. 2nd HARMONIC DISTORTION vs  $P_{OUT}$

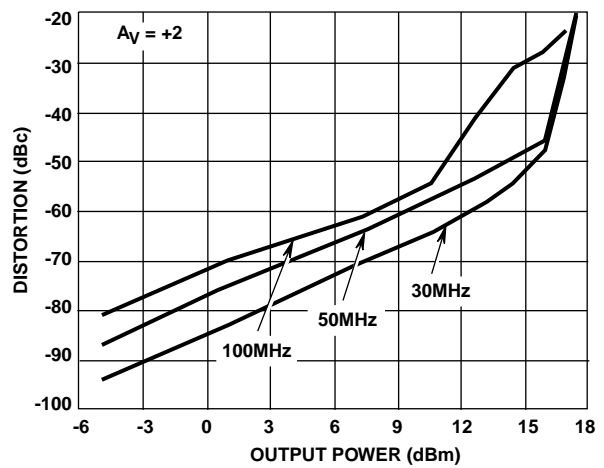


FIGURE 26. 3rd HARMONIC DISTORTION vs  $P_{OUT}$

**Typical Performance Curves**  $V_{SUPPLY} = \pm 5V$ ,  $T_A = 25^\circ C$ ,  $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

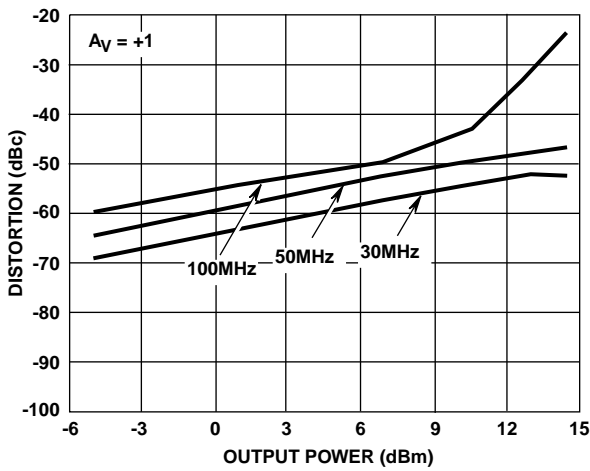


FIGURE 27. 2nd HARMONIC DISTORTION vs  $P_{OUT}$

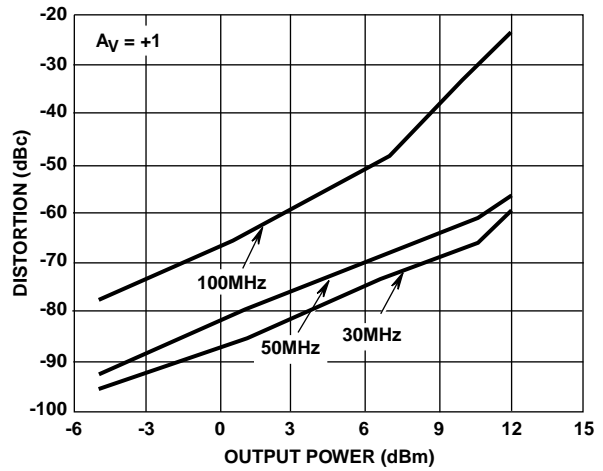


FIGURE 28. 3rd HARMONIC DISTORTION vs  $P_{OUT}$

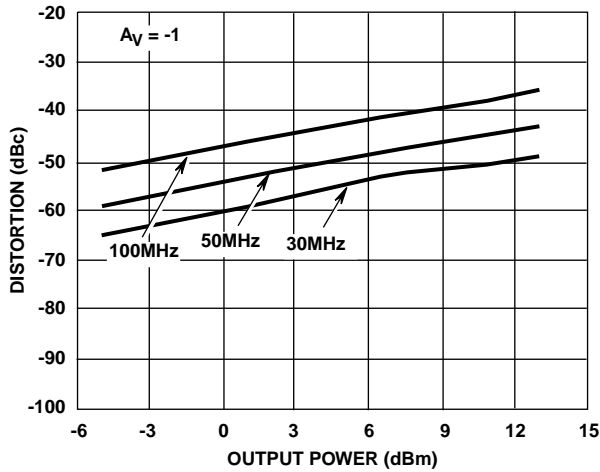


FIGURE 29. 2nd HARMONIC DISTORTION vs  $P_{OUT}$

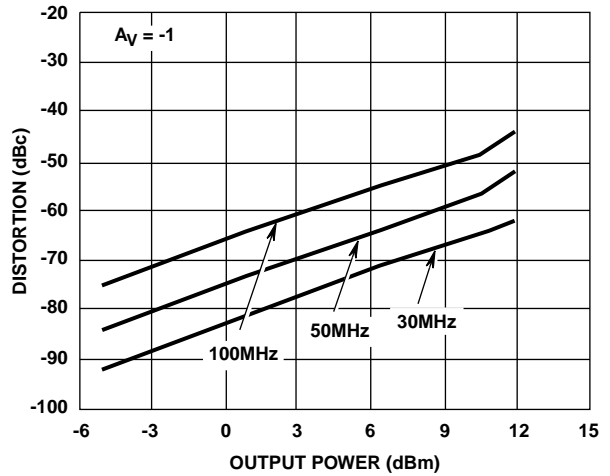


FIGURE 30. 3rd HARMONIC DISTORTION vs  $P_{OUT}$

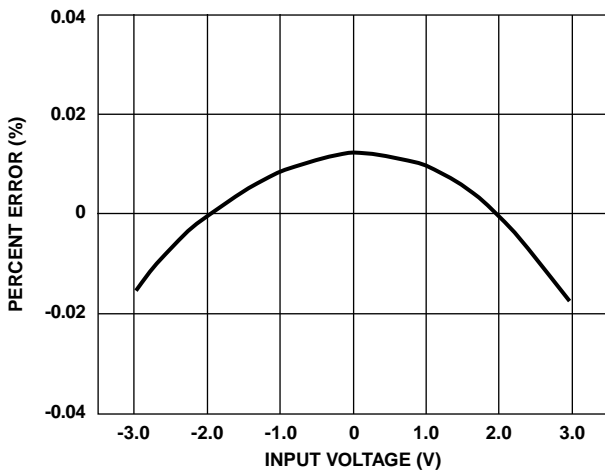


FIGURE 31. INTEGRAL LINEARITY ERROR

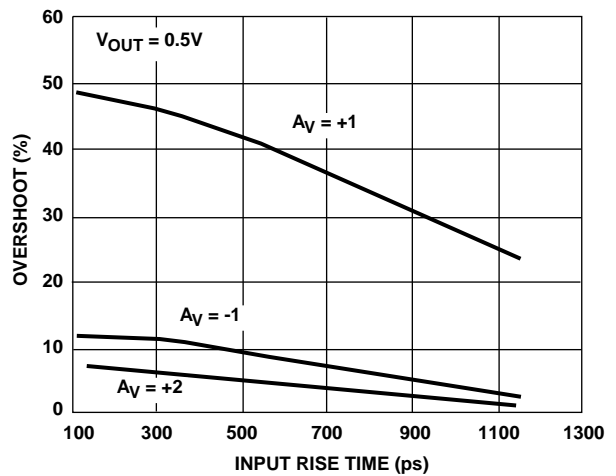


FIGURE 32. OVERSHOOT vs INPUT RISE TIME

**Typical Performance Curves**  $V_{SUPPLY} = \pm 5V$ ,  $T_A = 25^\circ C$ ,  $R_L = 100\Omega$ , Unless Otherwise Specified (Continued)

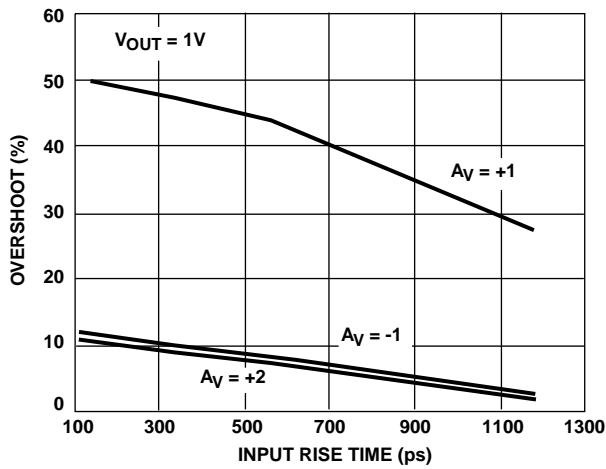


FIGURE 33. OVERSHOOT vs INPUT RISE TIME

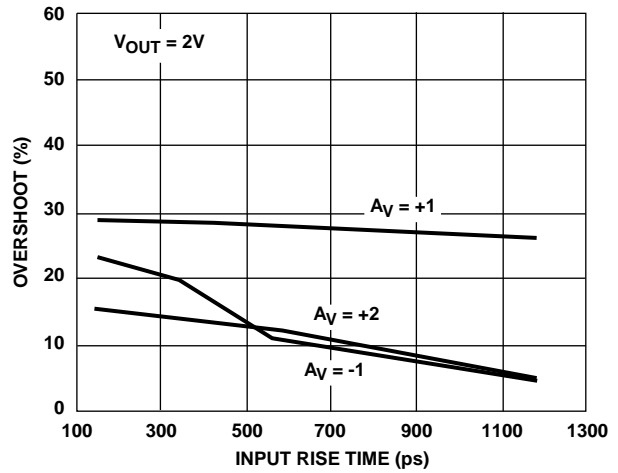


FIGURE 34. OVERSHOOT vs INPUT RISE TIME

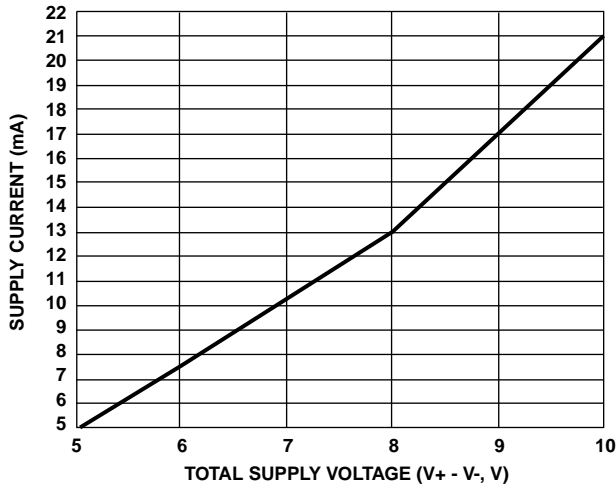


FIGURE 35. SUPPLY CURRENT vs SUPPLY VOLTAGE

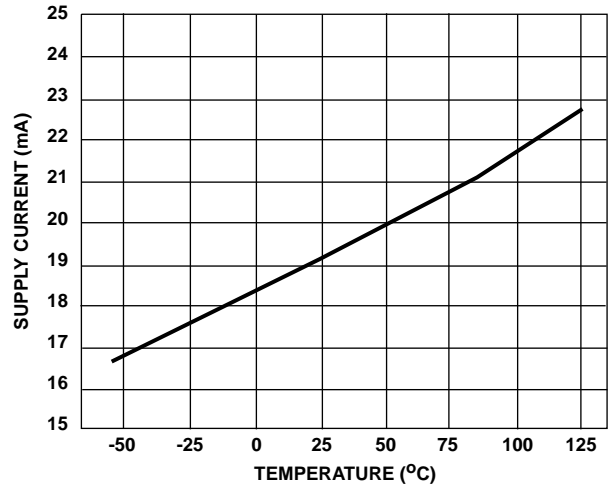


FIGURE 36. SUPPLY CURRENT vs TEMPERATURE

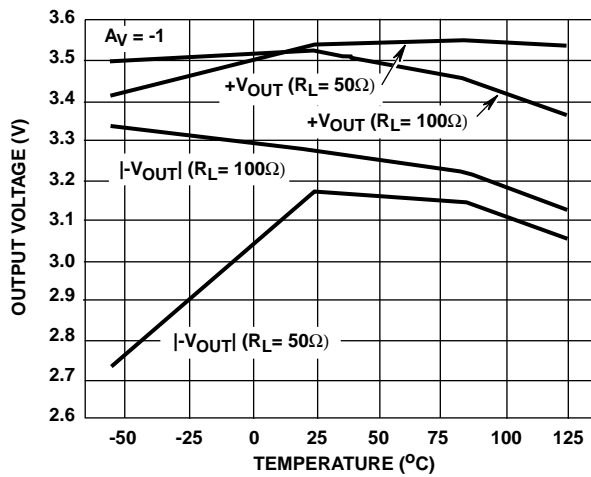


FIGURE 37. OUTPUT VOLTAGE vs TEMPERATURE

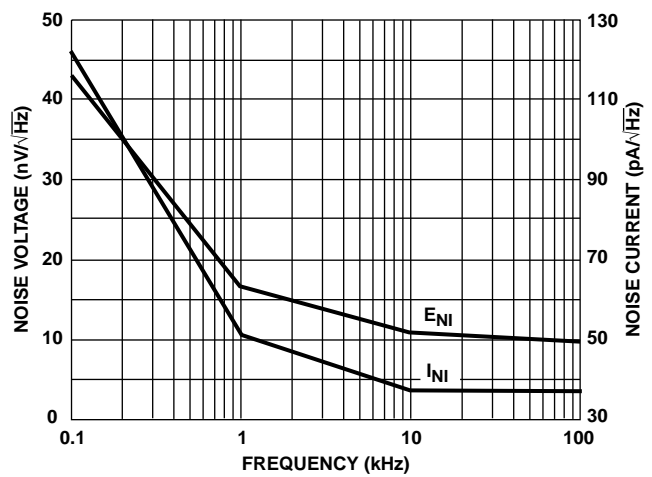


FIGURE 38. INPUT NOISE CHARACTERISTICS

# HFA1112

## Die Characteristics

### DIE DIMENSIONS:

63 mils x 44 mils x 19 mils  
1600 $\mu$ m x 1130 $\mu$ m 483 $\mu$ m

### METALLIZATION:

Type: Metal 1: AlCu (2%)/TiW  
Thickness: Metal 1: 8k $\text{\AA}$   $\pm$ 0.4k $\text{\AA}$   
Type: Metal 2: AlCu (2%)  
Thickness: Metal 2: 16k $\text{\AA}$   $\pm$ 0.8k $\text{\AA}$

### PASSIVATION:

Type: Nitride  
Thickness: 4k $\text{\AA}$   $\pm$ 0.5k $\text{\AA}$

### TRANSISTOR COUNT:

52

### SUBSTRATE POTENTIAL (Powered Up):

Floating (Recommend Connection to V-)

## Metallization Mask Layout

